



# CMOS High Voltage Logic – MM74C14

## Hex Schmitt Trigger Inverter in bare die form

Rev 1.0  
17/02/2023

### Description

The MM74C14 Hex Schmitt Trigger is a monolithic complementary MOS (CMOS) integrated circuit constructed with N-channel and P-channel enhancement transistors. The positive and negative going threshold voltages,  $V_{T+}$  and  $V_{T-}$ , show low variation with respect to temperature (typ.  $0.0005V/^{\circ}C$  at  $V_{CC} = 10V$ ), and hysteresis,  $V_{T+} - V_{T-} \geq 0.2 V_{CC}$  is guaranteed. All inputs are protected from damage due to static discharge by diode clamps to  $V_{CC}$  and GND.

### Features:

- Wide supply voltage range: 3V to 15V
- High noise immunity:  $0.70 V_{CC}$  (typ.)
- Low power TTL compatibility:
  - $0.40 V_{CC}$  (typ.)
  - $0.20 V_{CC}$  (guaranteed)
- Hysteresis:
  - $0.40 V_{CC}$  (typ.)
  - $0.20 V_{CC}$  (guaranteed).

### Ordering Information

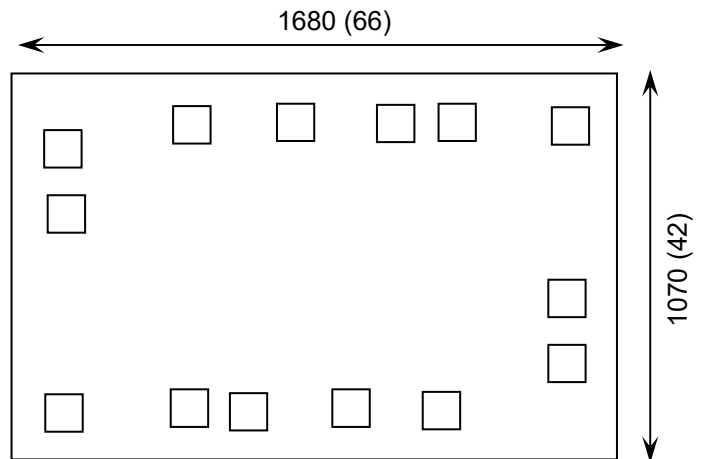
The following part suffixes apply:

- No suffix - MIL-STD-883 /2010B Visual Inspection

For High Reliability versions of this product please see

[MM54C14](#)

### Die Dimensions in $\mu m$ (mils)



### Supply Formats:

- Default – Die in Waffle Pack (100 per tray capacity)
- Sawn Wafer on Tape – On request
- Unsawn Wafer – On request
- Die Thickness  $\leftrightarrow$   $350\mu m$  (14 Mils) – On request
- Assembled into Ceramic Package – On request

### Mechanical Specification

Die Size (Unsawn)	1680 x 1070 66.14 x 42.13	$\mu m$ mils
Minimum Bond Pad Size	105 x 105 4.713 x 4.13	$\mu m$ mils
Die Thickness	350 ( $\pm 20$ ) 13.78 ( $\pm 0.79$ )	$\mu m$ mils
Top Metal Composition	Al 1%Si 1.1 $\mu m$	
Back Metal Composition	N/A – Bare Si	

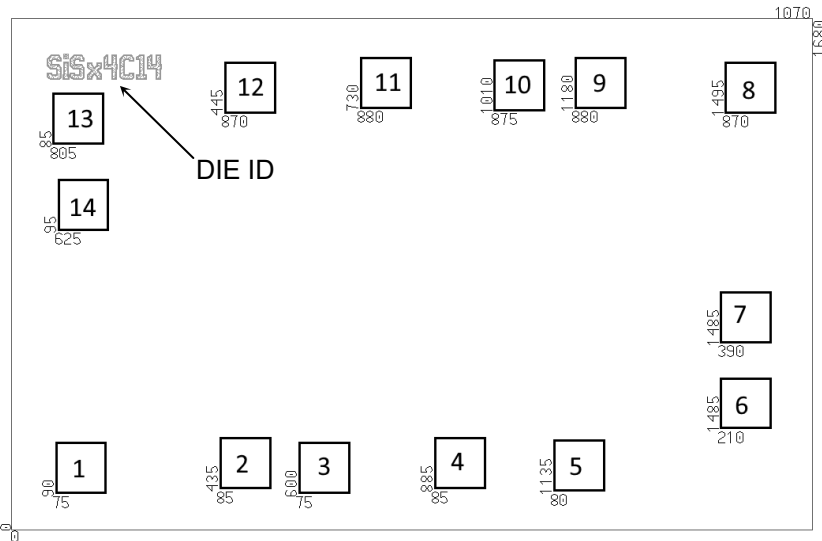




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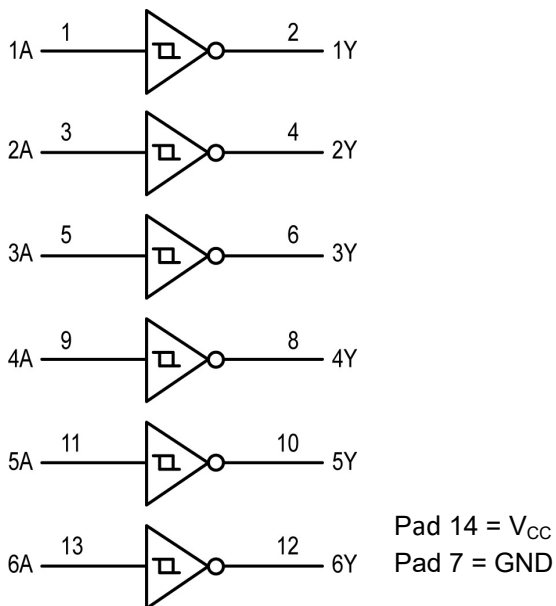
## Pad Layout and Functions



PAD	FUNCTION	COORDINATES (μm)	
		X	Y
1	1A	90	75
2	1Y	435	85
3	2A	600	75
4	2Y	885	85
5	3A	1135	80
6	3Y	1485	210
7	GND	1485	390
8	4Y	1495	870
9	4A	1180	880
10	5Y	1010	875
11	5A	730	880
12	6Y	445	870
13	6A	85	805
14	V <sub>CC</sub>	95	625

CONNECT CHIP BACK TO V<sub>CC</sub>

## Logic Diagram



## Function Table

INPUT A	OUTPUT Y
L	H
H	L





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## Absolute Maximum Ratings<sup>1</sup>

PARAMETER	SYMBOL	VALUE	UNIT
Voltage at any input pin	$V_{IN}$	-0.3 to $V_{CC} + 0.3$	V
Voltage at any output pin	$V_{OUT}$	-0.3 to $V_{CC} + 0.3$	V
Operating $V_{CC}$ range	$V_{CC}$	3 to 15	V
Absolute maximum $V_{CC}$	$V_{CC(MAX)}$	18	V
Maximum Power Dissipation <sup>2</sup>	$P_D$	700	mW
Operating Temperature Range	$T_A$	-40 to +85	°C
Storage Temperature Range	$T_{STG}$	-65 to +150	°C

1. Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability. 2. Measured in plastic DIP package, results in die form are dependent on die attach and assembly method.

## DC Electrical Characteristics $T_A = -40$ to $+85^\circ\text{C}$ unless otherwise stated

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
<b>CMOS TO CMOS</b>						
Positive Going Threshold Voltage	$V_{T+}$	$V_{CC} = 5V$	3.0	3.6	4.3	V
		$V_{CC} = 10V$	6.0	6.8	8.6	V
		$V_{CC} = 15V$	9.0	10.0	12.9	V
Negative Going Threshold Voltage	$V_{T-}$	$V_{CC} = 5V$	0.7	1.4	2.0	V
		$V_{CC} = 10V$	1.4	3.2	4.0	V
		$V_{CC} = 15V$	2.1	5.0	6.0	V
Hysteresis	$V_{T+} - V_{T-}$	$V_{CC} = 5V$	1.0	2.2	3.6	V
		$V_{CC} = 10V$	2.0	3.6	7.2	V
		$V_{CC} = 15V$	3.0	5.0	10.8	V
Logical "1" Output Voltage	$V_{OUT(1)}$	$V_{CC} = 5V, I_O = -10\mu A$	4.5	-	-	V
		$V_{CC} = 10V, I_O = -10\mu A$	9.0	-	-	V
Logical "0" Output Voltage	$V_{OUT(0)}$	$V_{CC} = 5V, I_O = 10\mu A$	-	-	0.5	V
		$V_{CC} = 10V, I_O = 10\mu A$	-	-	1.0	V
Logical "1" Input Current	$I_{IN(1)}$	$V_{CC} = 15V, V_{IN} = 15V$	-	0.005	1.0	$\mu A$
Logical "0" Input Current	$I_{IN(0)}$	$V_{CC} = 15V, V_{IN} = 0V$	-1.0	-0.005	-	$\mu A$
Supply Current	$I_{CC}$	$V_{CC} = 15V, V_{IN} = 0V/15V$	-	0.05	15	$\mu A$
Supply Current <sup>3</sup>	$I_{CC}$	$V_{CC} = 5V, V_{IN} = 2.5V$	-	20	-	$\mu A$
		$V_{CC} = 10V, V_{IN} = 5V$	-	200	-	$\mu A$
		$V_{CC} = 15V, V_{IN} = 7.5V$	-	600	-	$\mu A$

3. Only one of the six inputs is at  $\frac{1}{2} V_{CC}$ ; the others are either at  $V_{CC}$  or GND.





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## DC Electrical Characteristics $T_A = -40$ to $+85^\circ\text{C}$ unless otherwise stated

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
<b>CMOS/LPTTL INTERFACE</b>						
Logical "1" Input Voltage	$V_{IN(1)}$	$V_{CC} = 5\text{V}$	4.3	-	-	V
Logical "0" Input Voltage	$V_{IN(0)}$	$V_{CC} = 5\text{V}$	-	-	0.7	V
Logical "1" Output Voltage	$V_{OUT(1)}$	$V_{CC} = 4.75\text{V}$ , $I_O = -360\mu\text{A}$	2.4	-	-	V
Logical "0" Output Voltage	$V_{OUT(0)}$	$V_{CC} = 4.75\text{V}$ , $I_O = 360\mu\text{A}$	-	-	0.4	V
<b>OUTPUT DRIVE CURRENT <math>T_A = 25^\circ\text{C}</math></b>						
Output Source Current (P-Channel)	$I_{SOURCE}$	$V_{CC} = 5\text{V}$ , $V_{OUT} = 0\text{V}$	-1.75	-3.3	-	mA
		$V_{CC} = 10\text{V}$ , $V_{OUT} = 0\text{V}$	-8.0	-15	-	mA
Output Source Current (N-Channel)	$I_{SINK}$	$V_{CC} = 5\text{V}$ , $V_{OUT} = V_{CC}$	1.75	3.6	-	mA
		$V_{CC} = 10\text{V}$ , $V_{OUT} = V_{CC}$	8.0	16	-	mA
<b>DYNAMIC ELECTRICAL CHARACTERISTICS<sup>4</sup> <math>T_A = 25^\circ\text{C}</math>, <math>C_L = 50\text{pF}</math> unless otherwise stated</b>						
Propagation Delay from Input to Output	$t_{PD0}$ , $t_{PD1}$	$V_{CC} = 5\text{V}$	-	220	400	ns
		$V_{CC} = 10\text{V}$	-	80	200	ns
Input Capacitance	$C_{IN}$	Any Input	-	5.0	-	pF
Power Dissipation Capacitance <sup>5</sup>	$C_{PD}$	Per Gate	-	20	-	pF

4. Not production tested in die form, characterized by chip design.

5. Used to determine the no-load dynamic power consumption:  $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$ .

## Typical Characteristics

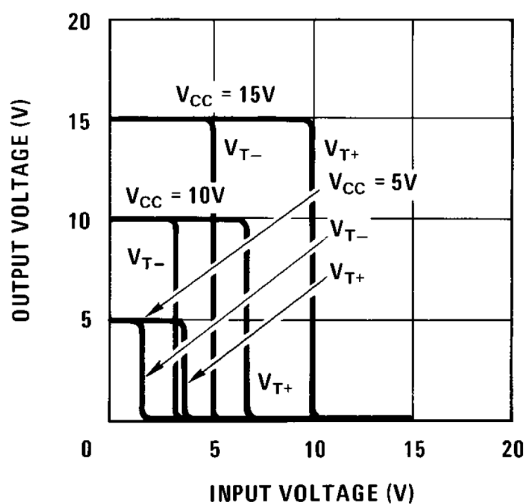


Figure 1 – Transfer Characteristics

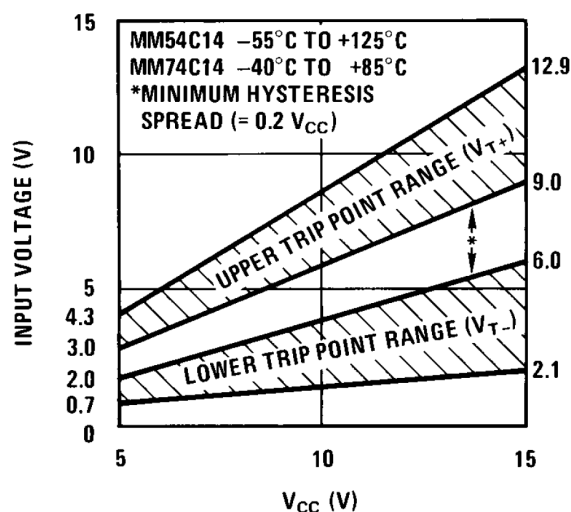


Figure 2 – Guaranteed Trip Point Range





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## Typical Characteristics continued

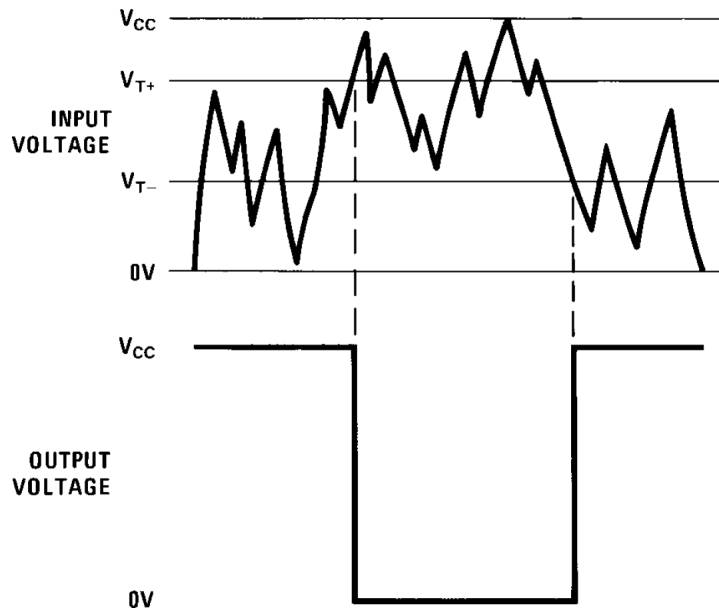


Figure 3 – Waveform

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